Supporting Information

Manuscript Title: Alternative SiO₂ surface energies direct MDCK epithelial behavior

Authors: Alan D. Covell¹, Zheng Zeng¹, Jianjun Wei¹, Amy Adamson², Dennis R. LaJeunesse¹*

¹Department of Nanoscience, Joint School of Nanoscience and Nanoengineering,

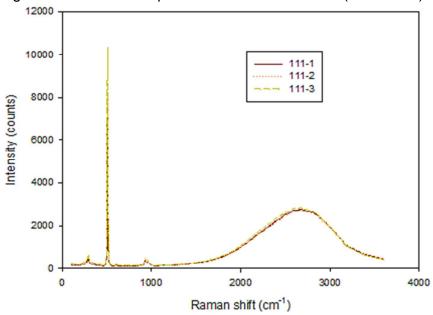
University of North Carolina at Greensboro, Greensboro, NC 27401, USA.

²Department of Biology, University of North Carolina at Greensboro, Greensboro, NC 27402, USA.

Supplemental Figure: 5 Supplemental Tables: 0

^{*} Corresponding Author: drlajeun@uncg.edu

Figure S1-Sn. Raman spectrum of <111> substrate (three trials).



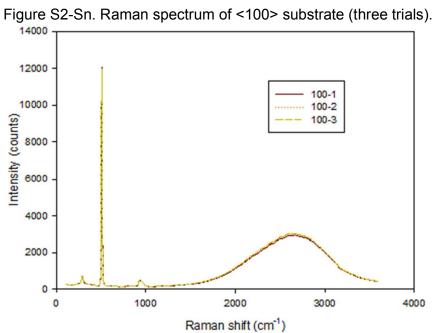
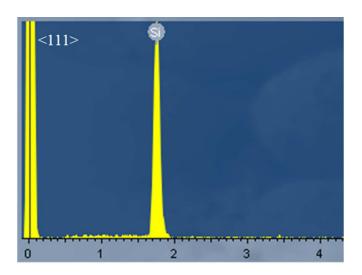


Figure S3-Sn: EDX analysis of <111> and <100> Si wafers



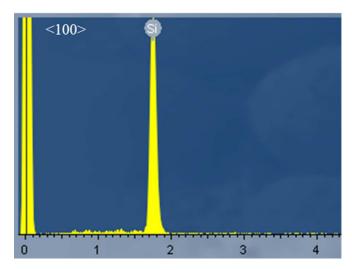


Figure S4-Sn. Epithelial Cell Growth on SiO_2 substrated, 1 and 4 day culture compared on 100-SiW, 111-SiW, and GCS both with standard RCA-1 cleaning, and plasma cleaning. Values are given as Percent Differences to GCS. The 100-SiW Growth was the only consistent statistically significant difference observed (n=5, p<0.05).

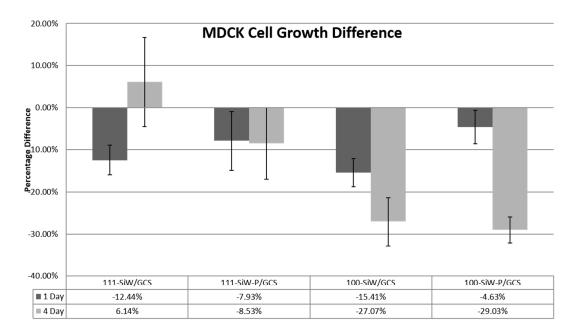


Figure S5-Sn: Confocal micrographs of the basal portion of MDCK epithelial cells demonstrating the expression of laminin (A-C) and collagen (D-F) in cells cultured on glass coverslip (A,D), <111> derived SiO_2 substrates (B,E), and <100> derived SiO_2 substrates (C. F). Note the upregulated of both ECM proteins in the cells cultured on <100> substrates when compared to cells cultured on other SiO_2 substrates.

